

25A, 35V - 150V Schottky Barrier Surface Mount Rectifier

FEATURES

- AEC-Q101 qualified
- Low power loss, high efficiency
- Ideal for automated placement
- Guard ring for overvoltage protection
- High surge current capability
- Moisture sensitivity level: level 1, per J-STD-020
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- Low voltage, high freq. inverter
- DC/DC converter
- Freewheeling diodes
- Reverse battery protection
- Car lighting

MECHANICAL DATA

- Case: TO-263AB (D²PAK)
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 1.37g (approximately)

KEY PARAMETERS					
PARAMETER VALUE UNI					
I _F	25	Α			
V_{RRM}	35 - 150	V			
I _{FSM}	200	Α			
T _{J MAX}	150	°C			
Package	TO-263AB (D ² PAK)				
Configuration	Dual dies				









TO-263AB (D²PAK)



ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)									
		MBRS	MBRS	MBRS	MBRS	MBRS	MBRS	MBRS	
PARAMETER	SYMBOL	2535	2545	2550	2560	2590	25100	25150	UNIT
		CTH	CTH	CTH	CTH	CTH	CTH	CTH	
Marking code on the device		MBRS 2535CT	MBRS 2545CT	MBRS 2550CT	MBRS 2560CT	MBRS 2590CT	MBRS 25100CT	MBRS 25150CT	
Repetitive peak reverse voltage	V_{RRM}	35	45	50	60	90	100	150	V
Reverse voltage, total rms value	$V_{R(RMS)}$	24	31	35	42	63	70	105	V
Forward current	I _F				25				Α
Surge peak forward current, 8.3ms single half sine wave superimposed on rated load	I _{FSM}		200						А
Peak repetitive reverse surge current ⁽¹⁾	I _{RRM}		1 0.5						Α
Peak repetitive forward current (Rated V _R , Square wave, 20KHz)	I _{FRM}	25					А		
Critical rate of rise of off- state voltage	dv/dt				10,000)			V/µs

Notes:

1. $tp = 2.0\mu s$, 1.0KHz



ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)									
PARAMETER	SYMBOL	MBRS 2535 CTH	MBRS 2545 CTH	MBRS 2550 CTH	MBRS 2560 CTH	MBRS 2590 CTH	MBRS 25100 CTH	MBRS 25150 CTH	UNIT
Junction temperature	TJ	-55 to +150						°C	
Storage temperature	T _{STG}		-55 to +150				°C		

THERMAL PERFORMANCE							
PARAMETER	SYMBOL	TYP	UNIT				
Junction-to-case thermal resistance	R _{eJC}	1	°C/W				

PARAMETER		CONDITIONS	SYMBOL	TYP	MAX	UNIT
MBRS2545 MBRS2550	MBRS2535CTH MBRS2545CTH			-	0.65	V
	MBRS2550CTH MBRS2560CTH	I _F = 12.5A, T _J = 25°C		-	0.75	V
	MBRS2590CTH MBRS25100CTH			-	0.85	V
	MBRS25150CTH			-	0.95	V
	MBRS2535CTH MBRS2545CTH		-	0.82	V	
Forward voltage per diode (1)	MBRS2550CTH MBRS2560CTH	I _F = 25.0A, T _J = 25°C	V _F	-	0.90	V
	MBRS2590CTH MBRS25100CTH			-	0.92	V
	MBRS25150CTH			-	1.02	V
	MBRS2535CTH MBRS2545CTH	I _F = 12.5A, T _J = 125°C		-	0.55	V
	MBRS2550CTH MBRS2560CTH			-	0.65	V
	MBRS2590CTH MBRS25100CTH			-	0.75	V
	MBRS25150CTH			-	0.92	V
	MBRS2535CTH MBRS2545CTH			-	0.73	V
	MBRS2550CTH MBRS2560CTH	I _F = 25.0A, T _{.1} = 125°C		-	0.80	V
	MBRS2590CTH MBRS25100CTH	, , , , , , , , , , , , , , , , , , , ,		-	0.88	V
	MBRS25150CTH			-	0.98	V



Taiwan Semiconductor

ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)						
PARAMETER		CONDITIONS	SYMBOL	TYP	MAX	UNIT
Reverse current @ rated V _R per diode ⁽²⁾	MBRS2535CTH MBRS2545CTH MBRS2550CTH MBRS2560CTH	T _J = 25°C	I _R	-	200	μA
	MBRS2590CTH MBRS25100CTH MBRS25150CTH			ı	100	μA
	MBRS2535CTH MBRS2545CTH	T _J = 125°C		ı	15	mA
	MBRS2550CTH MBRS2560CTH			ı	10	mA
	MBRS2590CTH MBRS25100CTH			-	7.5	mA
	MBRS25150CTH			-	5	mA

Notes:

- 1. Pulse test with PW = 0.3ms
- 2. Pulse test with PW = 30ms

ORDERING INFORMATION						
ORDERING CODE ⁽¹⁾	PACKAGE	PACKING				
MBRS25xCTH	TO-263AB (D ² PAK)	800 / Tape & Reel				

Notes:

1. "x" defines voltage from 35V(MBRS2535CTH) to 150V(MBRS25150CTH)



CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Fig.1 Forward Current Derating Curve

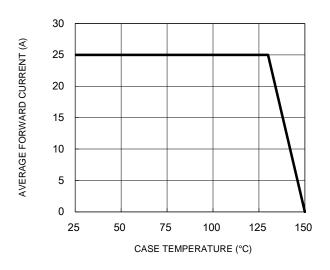


Fig.3 Typical Reverse Characteristics

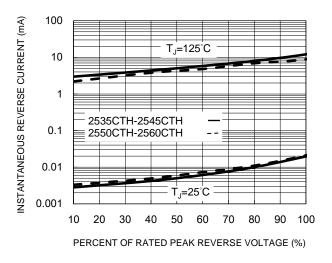


Fig.5 Typical Reverse Characteristics

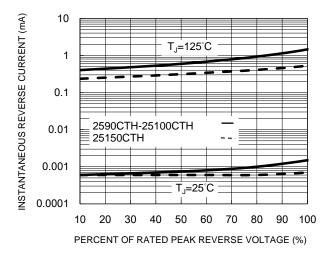


Fig.2 Typical Junction Capacitance

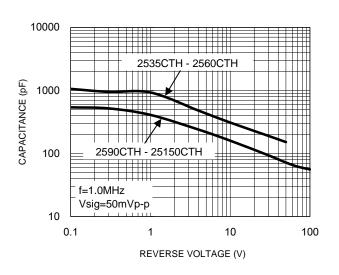


Fig.4 Typical Forward Characteristics

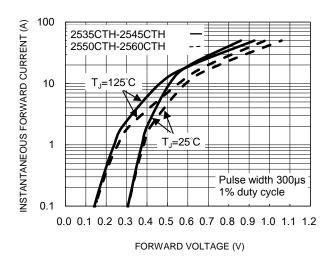
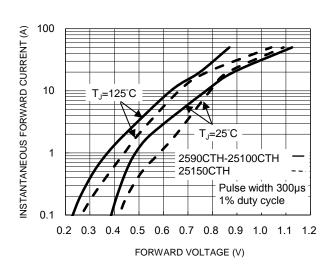


Fig.6 Typical Forward Characteristics





CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

Fig.7 Maximum Non-Repetitive Forward Surge Current

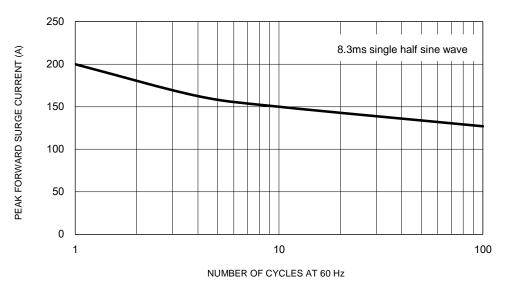
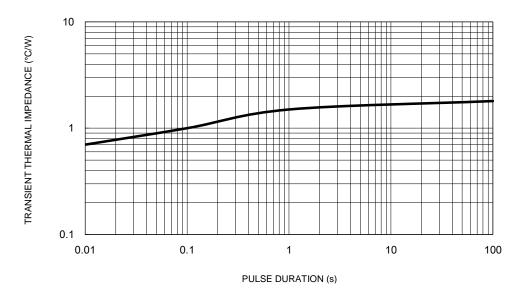


Fig.8 Typical Transient Thermal Impedance

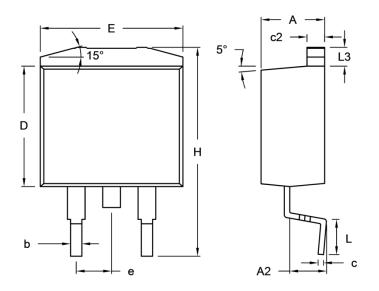




Taiwan Semiconductor

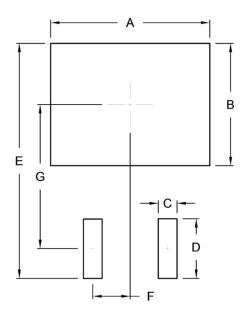
PACKAGE OUTLINE DIMENSIONS

TO-263AB (D²PAK)



DIM.	Unit (mm)		Unit ((inch)
DIN.	Min.	Max.	Min.	Max.
Α	4.44	4.70	0.175	0.185
A2	2.03	2.79	0.080	0.110
b	0.68	0.94	0.027	0.037
С	0.36	0.53	0.014	0.021
c2	1.14	1.40	0.045	0.055
D	8.25	9.25	0.325	0.364
E	-	10.50	-	0.413
е	2.41	2.67	0.095	0.105
Н	14.60	15.88	0.575	0.625
L	2.29	2.79	0.090	0.110
L3	1.14	1.40	0.045	0.055

SUGGESTED PAD LAYOUT



Symbol	Unit (mm)	Unit (inch)
Α	10.80	0.425
В	8.30	0.327
С	1.27	0.050
D	4.05	0.159
E	15.95	0.628
F	2.54	0.100
G	9.775	0.385

MARKING DIAGRAM



P/N = Marking Code G = Green Compound

YWW = Date Code F = Factory Code



Taiwan Semiconductor

Notice

Specifications of the products displayed herein are subject to change without notice. TSC or anyone on its behalf assumes no responsibility or liability for any errors or inaccuracies.

Purchasers are solely responsible for the choice, selection, and use of TSC products and TSC assumes no liability for application assistance or the design of Purchasers' products.

Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in TSC's terms and conditions of sale for such products, TSC assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of TSC products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify TSC for any damages resulting from such improper use or sale.